

aaa-035577

WLAN7102C

5 GHz Wi-Fi 6 Front-End IC

Rev. 4 — 15 September 2020

Product data sheet

1 General description

The WLAN7102C is a WLAN 5 GHz RF front-end IC in a 2 mm x 2 mm HWFLGA16 package.

The WLAN7102C is designed for Wi-Fi 6 applications. It includes a power amplifier with logarithmic power detector, a low noise receive amplifier (LNA) and a single pole double throw (SPDT) switch. The WLAN7102C also includes coexistence filters for both transmit and receive channels.

The device is matched to 50 Ω and integrates harmonic and out of band filtering which minimizes the layout area in the application.

2 Features and benefits

- Fully integrated Wi-Fi 6 RF front-end IC with high linearity and low-power modes
- $EVM_{dyn} = -43$ dB, 802.11ax MCS 10/11 HE80, $P_o = 14$ dBm
- Full high band 5150 MHz to 5925 MHz
- High-power efficiency
- Requires no external matching components, DC free input/output ports
- 3 TX operation modes enabling flexibility for power efficiency adaptation
- 2 RX operation modes enabling large gain step between LNA mode and Bypass mode
- Integrated logarithmic power detector
- ESD protection on all pins
 - Human Body Model (HBM) according to ANSI/ ESDA/JEDEC standard JS-001 exceeds 2 kV
 - Charged Device Model (CDM) according to ANSI/ESDA/JEDEC standard JS-002 exceeds 500 V
- Integrated RF decoupling capacitors for all V_{CC} and control pins

3 Applications

- Wi-Fi 6 support
- Smartphones, tablets, netbooks, and other portable computing devices
- Module applications for embedded systems



4 Quick reference data

Table 1. Quick reference data

$T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_{CC1} = V_{CC2} = V_{CC3} = 3.85\text{ V}$; $V_{IH} = 1.8\text{ V}$; $V_{IL} = 0\text{ V}$; $Z_s = Z_L = 50\text{ }\Omega$; $P_i = -30\text{ dBm}$ for RX, $P_i = -10\text{ dBm}$ for TX, $f = 5150\text{ MHz}$ to 5925 MHz . Unless otherwise specified. All values are measured at product input/output as reference plane. Measurements are done using the schematic in [Figure 5](#) and the components listed in [Table 14](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
RF performance from ANT to RX						
I _{CC}	supply current	RX_gain	-	11.5	-	mA
		RX_bypass mode	-	7.5	-	μA
G _p	power gain	RX_gain	-	16.2	-	dB
		RX_bypass mode	-	-5.4	-	dB
NF	noise figure	RX_gain	-	2.5	-	dB
P _{I(1dB)}	input power at 1 dB gain compression point	RX_gain	-	-9	-	dBm
RL _{in}	input return loss	RX_gain mode, return loss looking into ANT pin	-	9	-	dB
		RX_bypass mode, return loss looking into ANT pin	-	7.5	-	dB
RL _{out}	output return loss	RX_gain mode, return loss looking into RX pin	-	8.5	-	dB
		RX_bypass mode, return loss looking into RX pin	-	10	-	dB
RF performance from TX to ANT						
I _{CC}	supply current	TX_gain1a (11ax compliant mode), 22dBm_11a, 6 Mbp/s spectral mask compliant	-	335	-	mA
G _p	power gain	TX_gain1a (11ax compliant, high-power mode)	-	30.5	-	dB
		TX_gain2a (11ax compliant, 3 dB back-off mode)	-	27.5	-	dB
		TX_gain3 (11ax compliant, low-power mode)	-	16.5	-	dB
G _{flat}	gain flatness	all TX modes, for any 80 MHz bandwidth	-	+/-0.25	-	dB
		all TX modes, for entire frequency range	-	+/-0.75	-	dB
EVM _{dyn}	dynamic error vector magnitude	11ax MCS10/11 HE80, TX_gain1a, P _o = 14 dBm, 180 μs burst, 50 % duty cycle	-	-43	-	dB
RL _{in}	input return loss	return loss looking into TX pin	-	10	-	dB
RL _{out}	output return loss	return loss looking into ANT pin	-	8	-	dB
High Isolation performance from ANT to RX						
I _{CC}	supply current	high isolation (default)	-	7.5	-	μA
ISL _(ANT-RX)	ANT-RX isolation	high isolation (default)	35	-	-	dB

5 Ordering information

Table 2. Ordering information

Type number	Orderable part number	Package		
		Name	Description	Version
WLAN7102C	WLAN7102CZ	HWFLGA16	plastic, thermal enhanced ultra thin profile land grid array package; no leads; 16 terminals	SOT2013-2

6 Marking info

Table 3. Marking info

Type number	Marking
WLAN7102C	102

7 Functional diagram

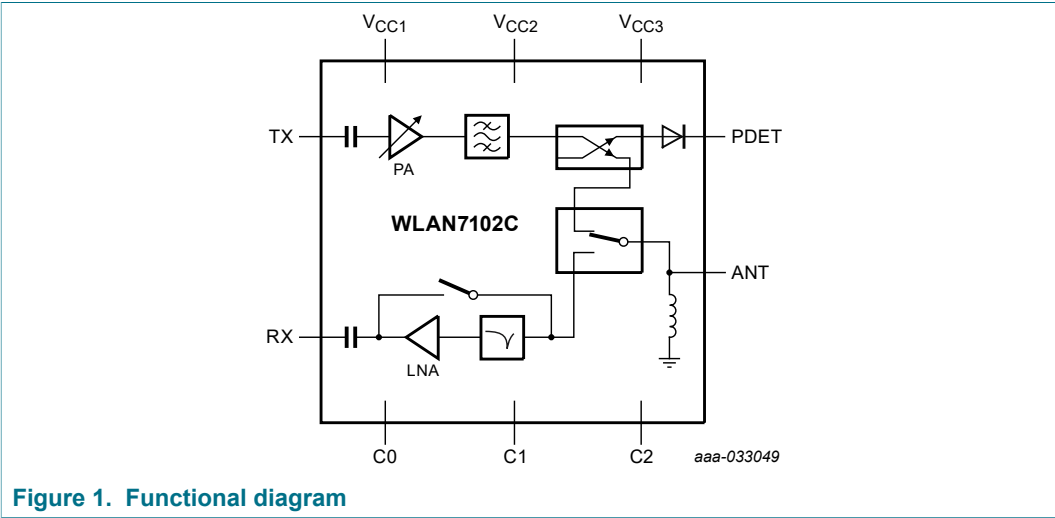
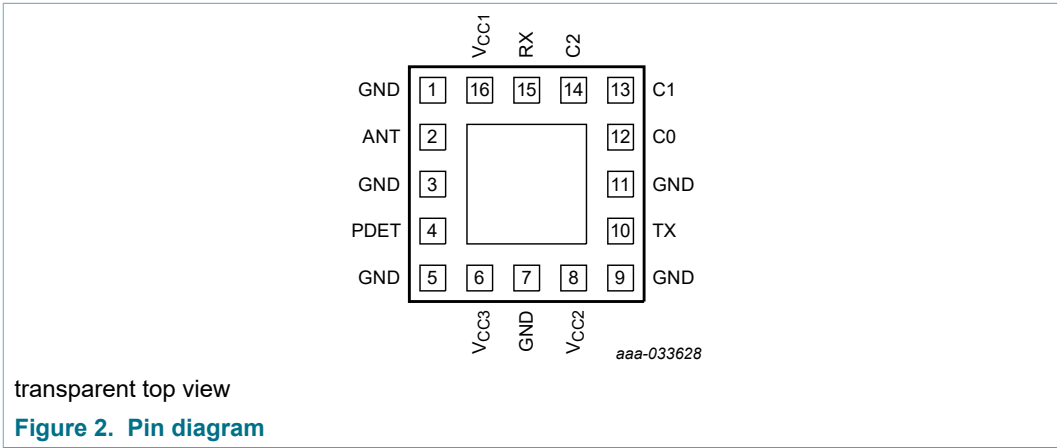


Figure 1. Functional diagram

8 Pinning information

8.1 Pinning diagram



8.2 Pin description

Table 4. Pin description

Pin	Symbol	Description
1,3,5,7,9, and 11	GND	ground
12	CO	control pin
13	C1	control pin
14	C2	control pin
15	RX	RX port
6	V _{CC3}	supply voltage
8	V _{CC2}	supply voltage
16	V _{CC1}	supply voltage
2	ANT	antenna port
4	PDET	power detector
10	TX	TX port

9 Functional description

9.1 Parallel interface control states

Table 5. Parallel interface control states

Control pin C0, C1, and C2 containing internal pull-down resistors.^[1]

C2	C1	C0	Signal path	Operating mode	Mode description	LNA bias	PA bias
0	0	0	-	-	high isolation (default)	off	off
0	0	1	TX to ANT	TX_gain1a	high gain, high linearity, 11ax compliant	off	on
1	0	1	TX to ANT	TX_gain2a	high gain, high linearity, 3 dB back off, 11ax compliant	off	on
1	1	1	TX to ANT	TX_gain3	low gain, low power, 11ax compliant	off	on
1	1	0	-	-	reserved	-	-
1	0	0	-	-	reserved	-	-
0	1	0	ANT to RX	RX_gain	normal gain	on	off
0	1	1	ANT to RX	RX_bypass	bypass	off	off

[1] Binary represented logic levels, where 0 denotes a logic low ($V_i \leq V_{IL}$) and 1 denotes a logic high ($V_i \geq V_{IH}$)

10 Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{CC}	supply voltage	6 V max 200 ms	-0.3	-	6	V
V _i	input voltage	applied to control pins C0, C1 and C2, digital control signals for RX, TX, and isolation modes	-0.3	-	4.2	V
P _i	input power	on ANT pin, RX LNA mode, MCS7 signal applied	-	-	10	dBm
		on ANT pin, RX Bypass mode, MCS0 signal applied	-	-	20	dBm
		on TX pin, MCS7 signal applied	-	-	10	dBm
		on TX pin, PA off, CW signal applied	-	-	15	dBm
TX_RUG	TX ruggedness (no irreversible damage)	V _{CC} : 3.2 V to 4.8 V, applied to TX_gain1a, and 1b modes, P _o = 24 dBm, MCS0 under 50 Ω load condition. The required P _i level is kept constant during ruggedness test, VSWR all phases	-	-	10:1	-
T _{stg}	storage temperature		-55	-	125	°C
T _j	junction temperature		-	-	175	°C
T _{mb}	mounting base temperature		-	-	100	°C
V _{ESD}	Electrostatic Discharge Voltage	Human Body Model (HBM) according to ANSI/ESDA/JEDEC standard JS-001	-	-	2	kV
		Charged Device Model (CDM) according to ANSI/ESDA/JEDEC standard JS-002	-	-	500	V

11 Recommended operating conditions

Table 7. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_{oper}	operating frequency		5150	-	5925	MHz
V_{CC}	supply voltage	on pin V_{CC1} , V_{CC2} , V_{CC3} ^[1]	3.2	3.85	4.8	V
V_{IH}	HIGH-level input voltage		1.6	1.8	3.6	V
V_{IL}	LOW-level input voltage		0.0	-	0.4	V
T_{amb}	ambient temperature		-40	25	85	°C

[1] Product is functional with reduced performance at supply voltages from 2.5 V to 3.2 V.

12 Thermal characteristics

Table 8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{\text{th(j-mb)}}$	junction to mounting base thermal resistance		-	45	-	K/W

13 Characteristics

13.1 Switching time performance

Table 9. Switching time performance

$T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_{CC1} = V_{CC2} = V_{CC3} = 3.85\text{ V}$; All ports are terminated with $50\text{ }\Omega$

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_{on(LNA)}$	LNA turn-on time	from 10 % to 90 % of LNA output level, bypass/LNA transition	-	170	500	ns
$t_{off(LNA)}$	LNA turn-off time	from 90 % to 10 % of LNA output level, bypass/LNA transition	-	230	500	ns
$t_{on(PA)}$	PA turn-on time	from 10 % to 90 % of PA output level, LNA/TX transition	-	250	500	ns
$t_{off(PA)}$	PA turn-off time	From 90 % to 10 % of PA output level, LNA/TX transition	-	250	500	ns

13.2 RF performance from ANT to RX

Table 10. RF performance from ANT to RX

$T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_{CC1} = V_{CC2} = V_{CC3} = 3.85\text{ V}$; $V_{IH} = 1.8\text{ V}$; $V_{IL} = 0\text{ V}$; All ports are terminated with $50\text{ }\Omega$; $P_i = -30\text{ dBm}$, $f = 5150\text{ MHz}$ to 5925 MHz . Unless otherwise specified. All values are measured at product input/output as reference plane. Measurements are done using the schematic in [Figure 5](#) and the components listed in [Table 14](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CC}	supply current	RX_gain	-	11.5	13.5	mA
		RX_gain, $T_{amb} = -20\text{ }^{\circ}\text{C}$ to $85\text{ }^{\circ}\text{C}$	-	-	14.5	mA
		RX_bypass	-	7.5	12	μA
		RX_bypass, $T_{amb} = -20\text{ }^{\circ}\text{C}$ to $85\text{ }^{\circ}\text{C}$, $V_{CC} = 4.8\text{ V}$	-	7.5	16	μA
G_p	power gain	RX_gain	13.4	16.2	18.8	dB
		RX_bypass	-7.9	-5.4	-2.4	dB
G_{flat}	power gain flatness	RX_gain, peak-to-peak over any 80 MHz band	-	+/-0.25	-	dB
		RX_gain, over full RF bandwidth	-	+/-0.75	-	dB
		RX_bypass, peak-to-peak over any 80 MHz band	-	+/-0.25	-	dB
		RX_bypass, over full RF bandwidth	-	+/-0.75	-	dB
NF	noise figure	RX_gain	-	2.5	2.8	dB
RL_{in}	input return loss	RX_gain mode, return loss looking into ANT pin	6.5	9	-	dB
		RX_bypass mode, return loss looking into ANT pin	5.5	7.5	-	dB
RL_{out}	output return loss	RX_gain mode, return loss looking into RX pin	7	8.5	-	dB
		RX_bypass mode, return loss looking into RX pin	8	10	-	dB
$IP3_i$	input third intercept point	RX_gain ^[1]	-	2.5	-	dBm
		RX_bypass ^[1]	-	20.5	-	dBm
$P_{i(1dB)}$	input power at 1 dB gain compression point	RX_gain	-10.5	-9	-	dBm
		RX_bypass	11.5	14	-	dBm

[1] $P_i = -20\text{ dBm/}$ tone, (10 MHz to 20 MHz tone spacing)

13.3 RF performance from TX to ANT

Table 11. RF performance from TX to ANT

$T_{amb} = 25\text{ °C}$; $V_{CC1} = V_{CC2} = V_{CC3} = 3.85\text{ V}$; $V_{IH} = 1.8\text{ V}$; $V_{IL} = 0\text{ V}$; All ports are terminated with $50\text{ }\Omega$; $P_i = -10\text{ dBm}$, $f = 5150\text{ MHz}$ to 5925 MHz . Unless otherwise specified. All values are measured at product input/output as reference plane. Measurements are done using the schematic in [Figure 5](#) and the components listed in [Table 14](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CC}	supply current	TX_gain1a, no RF	-	190	214	mA
		TX_gain1a, no RF, $T_{amb} = -20\text{ °C}$ to 85 °C	-	-	227	mA
		TX_gain2a, no RF	-	145	160	mA
		TX_gain2a, no RF, $T_{amb} = -20\text{ °C}$ to 85 °C	-	-	170	mA
		TX_gain3, no RF	-	57	67	mA
		TX_gain3, no RF, $T_{amb} = -20\text{ °C}$ to 85 °C	-	-	74	mA
		TX_gain1a, $P_o = 16\text{ dBm}$, 11ax MCS10/11 HE80	-	230	250	mA
		TX_gain1a, $P_o = 17.5\text{ dBm}$, 11ac MCS9 VHT80	-	250	270	mA
		TX_gain1a, $P_o = 19\text{ dBm}$, 11n MCS7 HT20	-	270	293	mA
		TX_gain1a, $P_o = 22\text{ dBm}$, 11a OFDM6, 20 MHz	-	339	367	mA
		TX_gain1a, $P_o = 22\text{ dBm}$, 11a OFDM6, 20 MHz, $T_{amb} = -20\text{ °C}$ to 85 °C	-	-	382	mA
		TX_gain2a, $P_o = 13\text{ dBm}$, 11ac MCS9 VHT80	-	170	185	mA
		TX_gain2a, $P_o = 16\text{ dBm}$, 11n MCS7 HT20	-	200	218	mA
		TX_gain3, $P_o = 4\text{ dBm}$, 11ax MCS10/11 HE80	-	62	71	mA
		TX_gain3, $P_o = 4\text{ dBm}$, 11ax MCS10/11 HE80, $T_{amb} = -20\text{ °C}$ to 85 °C	-	-	75	mA
G_p	power gain	TX_gain1a mode	27.5	30.5	33.5	dB
		TX_gain1a mode, $T_{amb} = -20\text{ °C}$ to 85 °C	25.5	-	35	dB
		TX_gain2a mode	25	27.5	30	dB
		TX_gain2a mode, $T_{amb} = -20\text{ °C}$ to 85 °C	23	-	31.5	dB
		TX_gain3 mode	14.5	16.5	18.5	dB
		TX_gain3 mode, $T_{amb} = -20\text{ °C}$ to 85 °C	13.5	-	19.5	dB
G_{flat}	gain flatness	all TX modes, for any 80 MHz bandwidth	-	+/-0.25	-	dB
		all TX modes, for entire frequency range	-	+/-0.75	-	dB
RL_{in}	input return loss	all TX modes, return loss looking into TX pin	8	10	-	dB
RL_{out}	output return loss	all TX modes, return loss looking into ANT pin	6	8	-	dB
$ISL_{(ANT-RX)}$	ANT-RX isolation	all TX modes, measured between ANT, and RX pins	33	-	-	dB
SEM margin	margin to spectrum emission mask	11a OFDM6, 20 MHz				
		TX_gain1a, $P_o = 22\text{ dBm}$	1	3.5	-	dB
		11n MCS0, 20 MHz				
		TX_gain1a, $P_o = 21\text{ dBm}$	1	3	-	dB

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
EVM _{dyn}	dynamic error vector magnitude	11a OFDM6, 20 MHz, 180 µs, 50 % duty cycle				
		TX_gain1a, P _o = 22 dBm	-	-20	-18	dB
		TX_gain1a, P _o = 22 dBm, T _{amb} = -20 °C to 85 °C	-	-	-16.5	dB
		11n MCS0, 20 MHz, 180 µs, 50 % duty cycle				
		TX_gain1a, P _o = 20.6 dBm	-	-25	-23	dB
		TX_gain1a, P _o = 20.6 dBm, T _{amb} = -20 °C to 85 °C	-	-	-20.5	dB
		11a OFDM54, 20 MHz, 180 µs, 50 % duty cycle				
		TX_gain1a, P _o = 19.5 dBm	-	-31	-29	dB
		TX_gain1a, P _o = 19 dBm, T _{amb} = -20 °C to 85 °C	-	-	-26	dB
		11n MCS7 HT20, 180 µs, 50 % duty cycle				
		TX_gain1a, P _o = 18.5 dBm	-	-36	-33.5	dB
		TX_gain1a, P _o = 18.5 dBm, T _{amb} = -20 °C to 85 °C	-	-	-28	dB
		TX_gain2a, P _o = 15.5 dBm	-	-33	-28.5	dB
		TX_gain2a, P _o = 15.5 dBm, T _{amb} = -20 °C to 85 °C	-	-	-27	dB
		11n MCS7 HT40, 180 µs, 50 % duty cycle				
		TX_gain1a, P _o = 18.5 dBm	-	-36	-33.5	dB
		TX_gain2a, P _o = 15.5 dBm	-	-33	-28.5	dB
		11ac MCS9 VHT80, 180 µs, 50 % duty cycle				
		TX_gain1a, P _o = 17 dBm	-	-40	-36.5	dB
		TX_gain1a, P _o = 17 dBm, T _{amb} = -20 °C to 85 °C	-	-	-33	dB
		TX_gain2a, P _o = 14 dBm	-	-39	-35	dB
		TX_gain2a, P _o = 14 dBm, T _{amb} = -20 °C to 85 °C	-	-	-32	dB
		11ac MCS9 VHT160, 180 µs, 50 % duty cycle				
		TX_gain1a, P _o = 17 dBm	-	-38	-34.5	dB
		11ax MCS10/11 HE80, 180 µs, 50 % duty cycle				
		TX_gain1a, P _o = 16 dBm	-	-42.5	-38.5	dB
		TX_gain1a, P _o = 16 dBm, T _{amb} = -20 °C to 85 °C	-	-	-35.5	dB
		TX_gain1a, P _o = 14 dBm	-	-43	-39	dB
		TX_gain1a, P _o = 14 dBm, T _{amb} = -20 °C to 85 °C	-	-	-36.5	dB
		TX_gain2a, P _o = 11 dBm	-	-42.5	-38	dB
		TX_gain2a, P _o = 11 dBm, T _{amb} = -20 °C to 85 °C	-	-	-36.5	dB
		TX_gain3, P _o = 4 dBm	-	-44	-40.5	dB
		TX_gain3, P _o = 4 dBm, T _{amb} = -20 °C to 85 °C	-	-	-39.5	dB
		11ax MCS10/11 HE160, 180 µs, 50 % duty cycle				
		TX_gain1a, P _o = 13 dBm	-	-42.5	-38.5	dB

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$\alpha 2H$	second harmonic emission level	11a OFDM6				
		TX_gain1a, $P_o = 22$ dBm	-	-23	-18.5	dBm/MHz
$\alpha 3H$	third harmonic emission level	11a OFDM6				
		TX_gain1a, $P_o = 22$ dBm	-	-21	-17	dBm/MHz

13.4 High isolation performance from ANT to RX

Table 12. High isolation performance from ANT to RX

$T_{amb} = 25$ °C; $V_{CC1} = V_{CC2} = V_{CC3} = 3.85$ V; $V_{IH} = 1.8$ V; $V_{IL} = 0$ V; All ports are terminated with 50 Ω ; $f = 5150$ MHz to 5925 MHz. Unless otherwise specified. All values are measured at product input/output as reference plane. Measurements are done using the schematic in [Figure 5](#) and the components listed in [Table 14](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CC}	supply current	high isolation (default)	-	7.5	-	μ A
$ISL_{(ANT-RX)}$	ANT-RX isolation	high isolation (default)	35	-	-	dB

13.5 Power detector

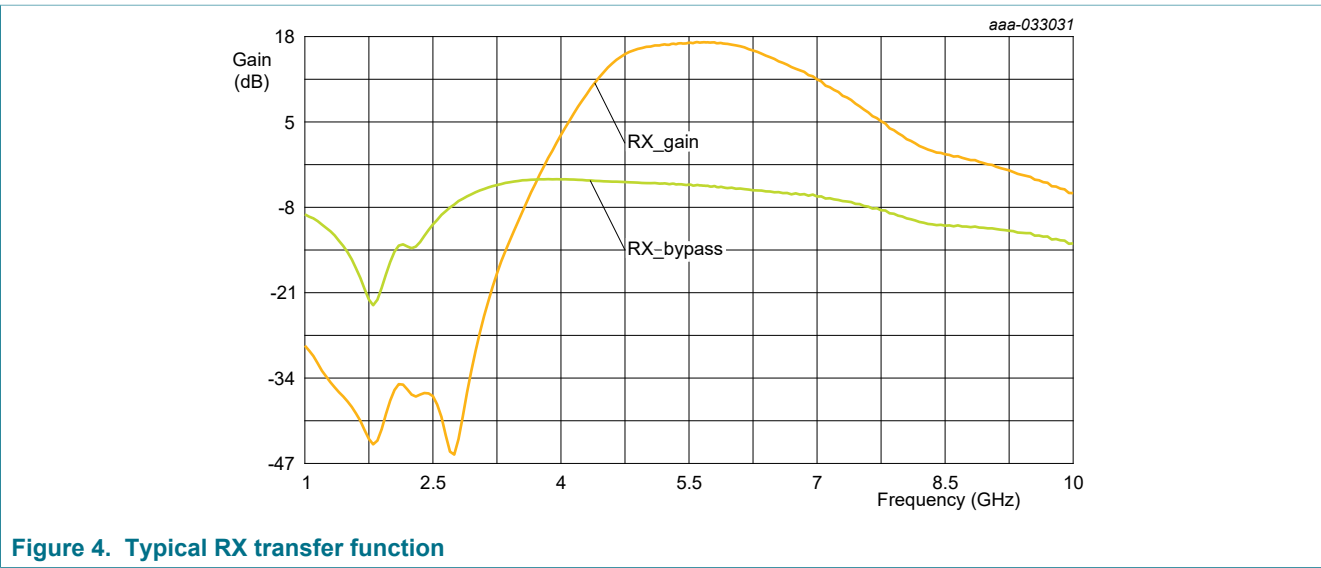
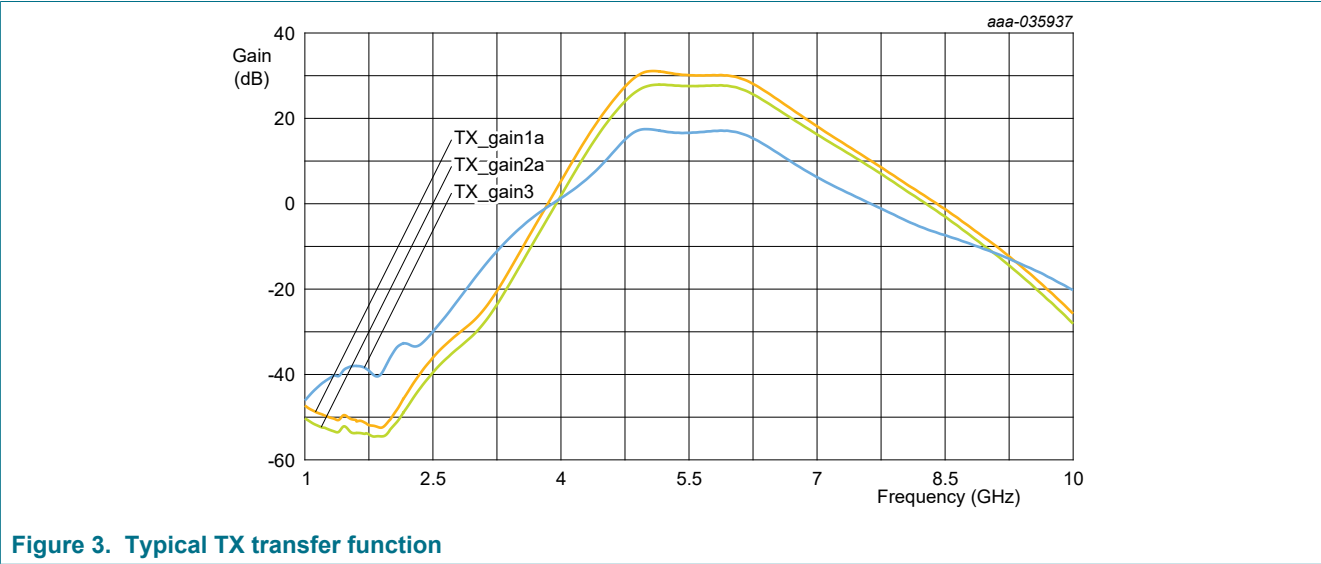
Table 13. Power detector performance

$T_{amb} = 25$ °C; $V_{CC1} = V_{CC2} = V_{CC3} = 3.85$ V; $V_{IH} = 1.8$ V; $V_{IL} = 0$ V; All ports are terminated with 50 Ω ; $f = 5150$ MHz to 5925 MHz. Unless otherwise specified. All values are measured at product input/output as reference plane. Measurements are done using the schematic in [Figure 5](#) and the components listed in [Table 14](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{det}	detected voltage	$P_o = 0$ dBm, $f = 5400$ MHz ^[1]	180	290	340	mV
		$P_o = 22$ dBm $f = 5400$ MHz ^[1]	760	935	1050	mV
$V_{det(flat)}$	detected voltage flatness across the band	$P_o = 0$ dBm to 22 dBm	-	-	1.5	dB

[1] Measured at the peak of the preamble of the OFDM signal, 11a 6 Mbps applied

14 Graphics



15 Application information

Application schematic shows a typical application for WLAN7102C. TX output stage can draw 250 mA of total output stage current from Vcc3. Each of RF pins except the antenna port has an internal DC-cut capacitor and tuned to 50 Ohm termination impedance. There is no need for any external DC-cut or matching component in a 50 ohm-to-50 ohm application. All the supply pins are RF decoupled internally, so one capacitor (100 nF) per supply pin is sufficient for WLAN envelope-content filtering in a typical application. Nevertheless, as for precaution, a 6.8 pF RF decoupling capacitor close to Vcc1 pin can improve the supply immunity of WLAN7102C in the final application. A large capacitor (Ce) performs a low frequency filtering (for supply noise or jitter). Control pins (C0, C1, C2) are also RF decoupled internally, so there is no need for external decoupling use, as long as the control lines are not polluted by any aggressor devices in the application.

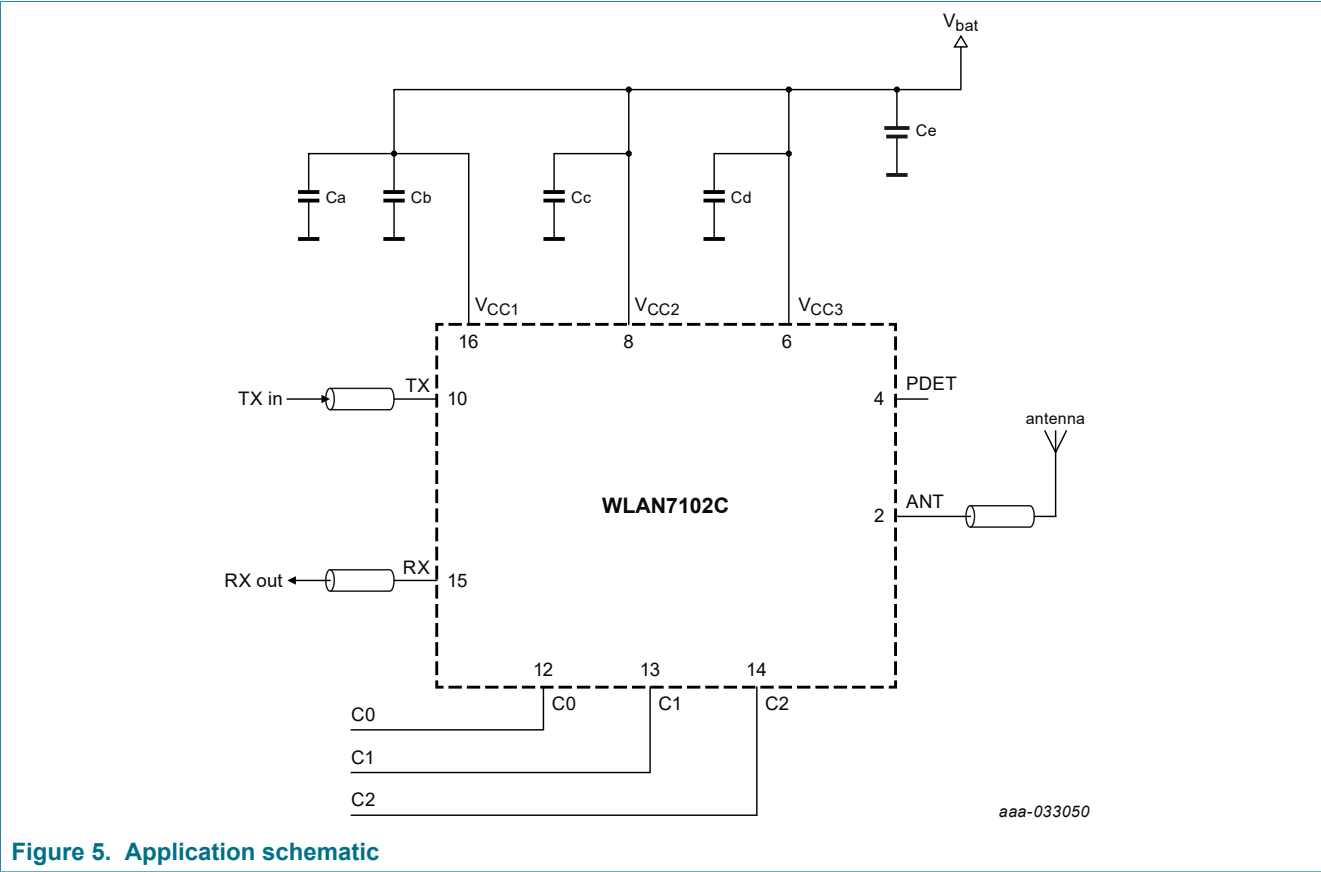
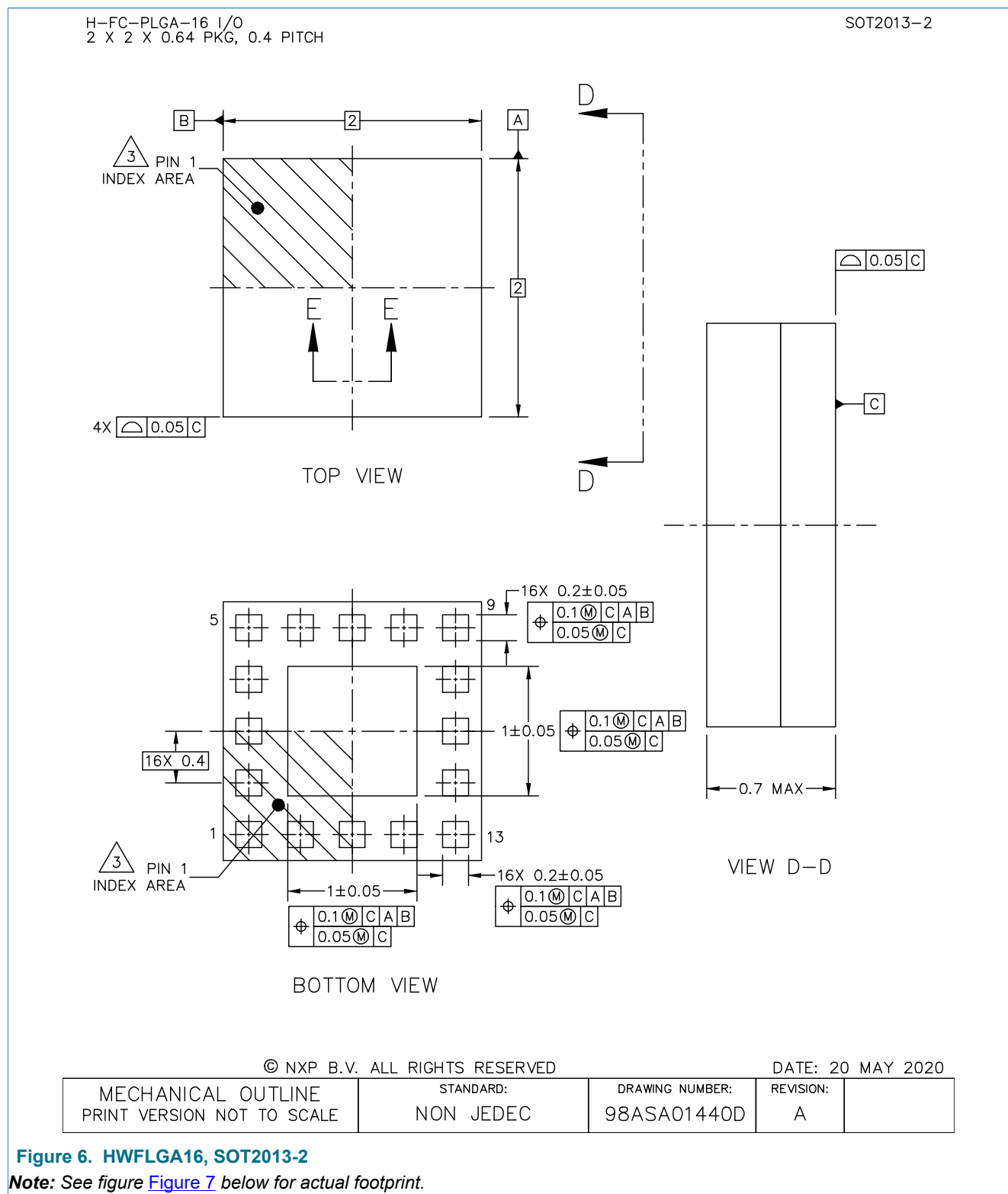
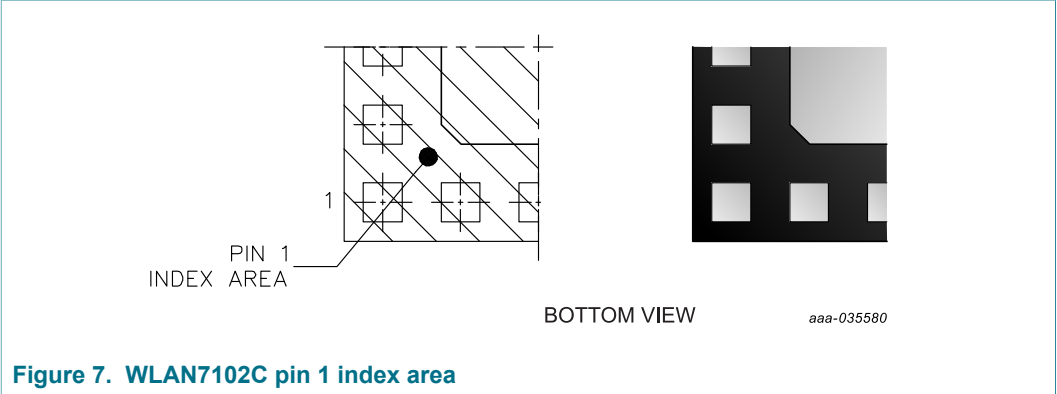


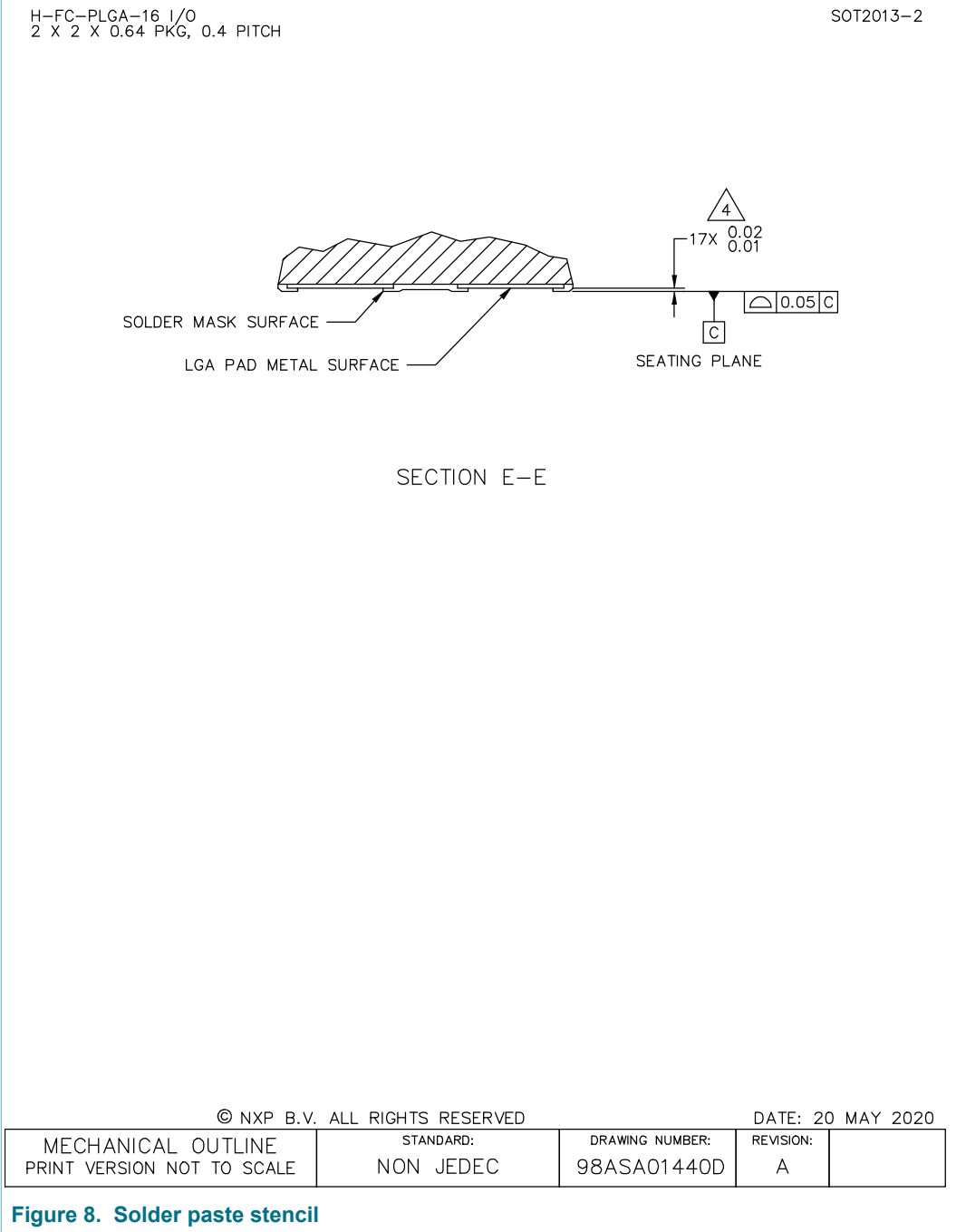
Table 14. List of components

Component	Description	Value	Amount	Remarks
Ca, Cc, Cd.	capacitor	100 nF	3	
Cb	capacitor	6.8 pF	1	
Ce	capacitor	≥ 10 μF	1	





16.1 Footprint and solder information



NXP recommends by default to apply the soldering and footprint guidelines as are released in POD SOT2013-2.

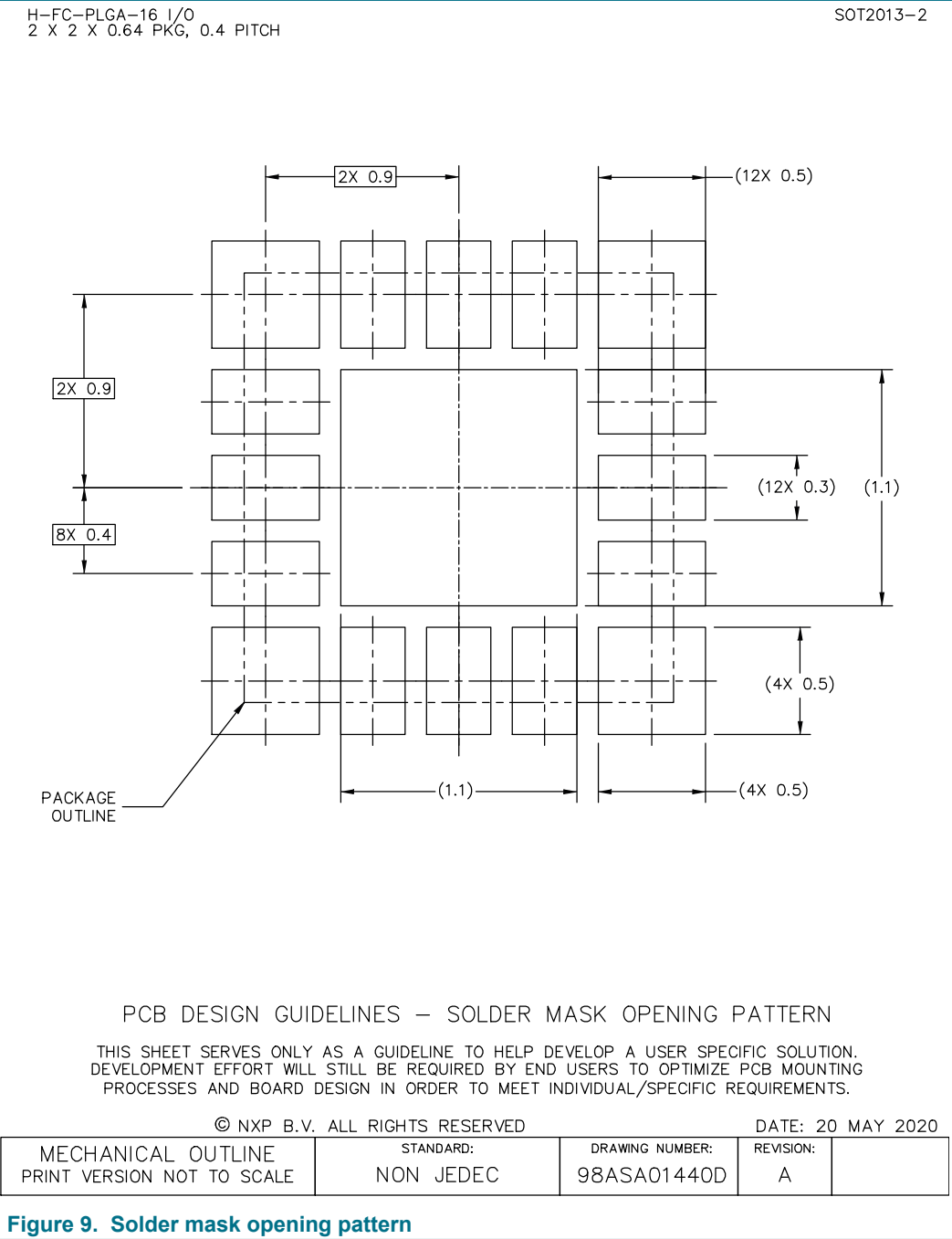
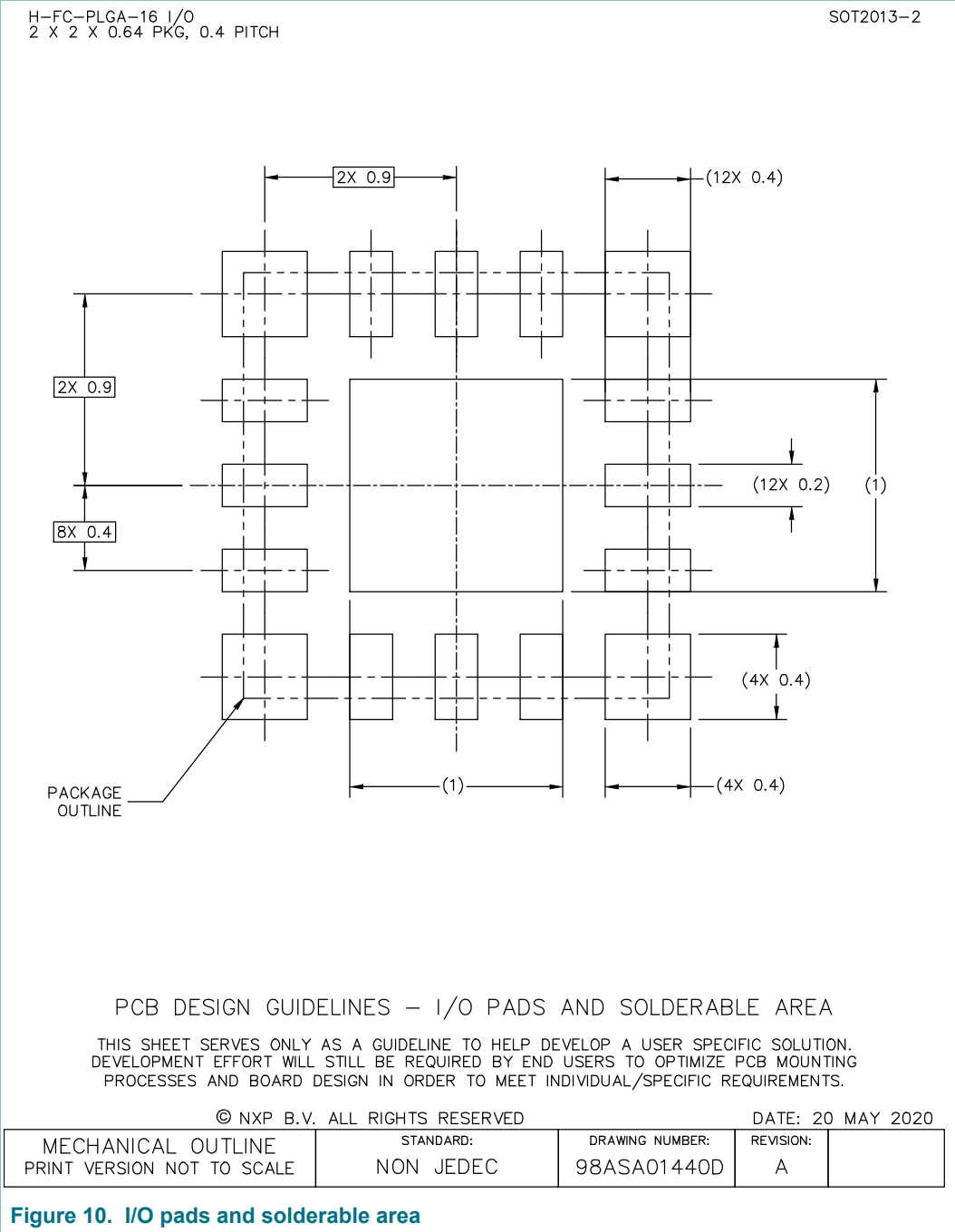
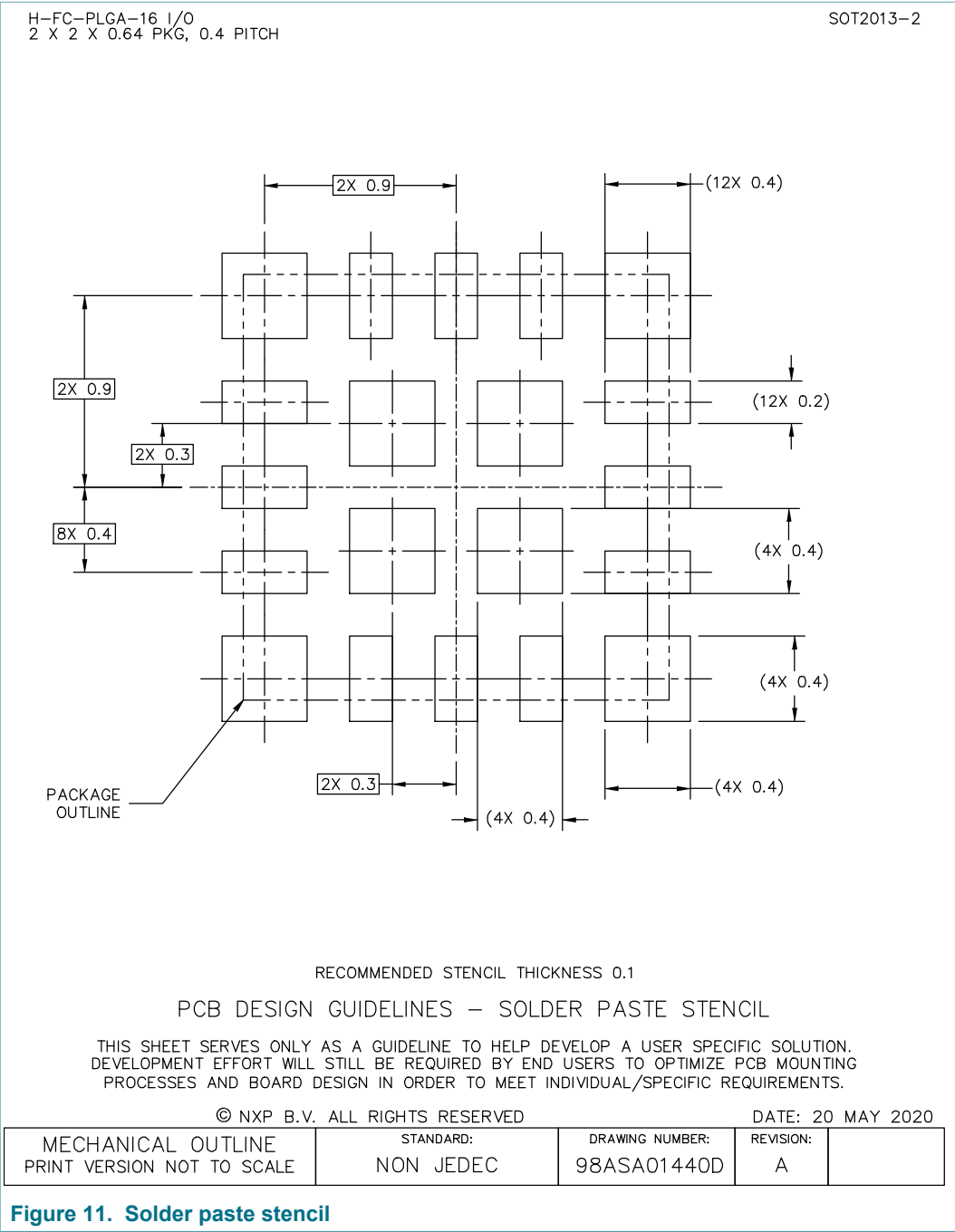


Figure 9. Solder mask opening pattern





17 Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices. Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

18 Abbreviations

Table 15. Abbreviations

Acronym	Description
ANT	antenna
CDM	charge device model
CW	continuous wave
DC	direct current
ESD	electrostatic discharge
EVM	error vector magnitude
FEIC	front end-integrated circuit
HBM	human body model
ISM	industrial scientific medical
ISL	isolation
LTE_LAA	LTE licensed assisted access
MCS	modulation code scheme
MIMO	multiple in multiple out
MSL	moisture sensitivity level
NF	noise figure
PA	power amplifier
RF	radio frequency
WLAN	wireless local area network

19 Revision history

Table 16. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
WLAN7102C v.4	20200915	Product data sheet	-	WLAN7102C v.3
modification	<ul style="list-style-type: none"> • Changed status from Company confidential to Public • updated the ESD condition on CDM with the correct description of the used ESD standard • added solder information to the data sheet 			
WLAN7102C v.3	20191210	Product data sheet	-	WLAN7102C v.2
modification	<ul style="list-style-type: none"> • changed some conditions and values on EVM parameter for TX to ANT, on 11a OFDM54, and 11n MCS7 HT20 • added extra conditions and values on EVM parameter for TX to ANT, 11n MCS7 HT40, 11ac MCS9 VHT160, and 11ax MCS10/11 HE160 			
WLAN7102C v.2	20191128	Product data sheet	-	WLAN7102C v.1
modification	<ul style="list-style-type: none"> • changed minimum value on detected voltage to 760 mV on $P_o = 22 \text{ dBm}$ $f = 5400 \text{ MHz}$ condition 			
WLAN7102C v.1	20191122	Product data sheet	-	-

20 Legal information

20.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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